xxxFN (JEDEC SOP) is not available in

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

## TC74VHC238F,TC74VHC238FN,TC74VHC238FT,TC74VHC238FK

Note:

#### 3-to-8 Line Decoder

The TC74VHC238 is an advanced high speed CMOS 3-to-8 DECODER fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

When the device is enabled, 3 Binary Select inputs (A, B and C) determine which one of the outputs (Y0-Y7) will go High.

When enable input G1 is held low or either  $\overline{G}2A$  or  $\overline{G}2B$  is held high, decoding function is inhibited and all outputs go Low.

G1 G2A, and G2B inputs are provided to ease cascade connection and for use as an address decoder for memory systems.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

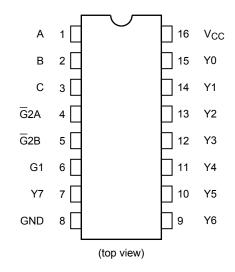
#### Features

- High speed:  $t_{pd} = 5.5 \text{ ns}$  (typ.) at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 4 \mu A (max)$  at  $Ta = 25^{\circ}C$
- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V<sub>CC</sub> (opr) = 2 to 5.5 V
- Pin and function compatible with 74ALS238

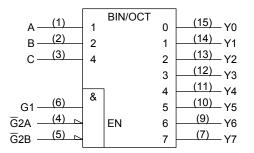
Japan. TC74VHC238F सप्तमाम SOP16-P-300-1.27A TC74VHC238FN SOL16-P-150-1.27 TC74VHC238FT TSSOP16-P-0044-0.65A TC74VHC238FK VSSOP16-P-0030-0.50 Weight SOP16-P-300-1.27A : 0.18 g (typ.) SOL16-P-150-1.27 : 0.13 g (typ.) TSSOP16-P-0044-0.65A : 0.06 g (typ.) VSSOP16-P-0030-0.50 : 0.02 g (typ.)

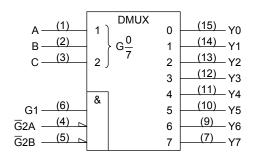
# <u>TOSHIBA</u>

### **Pin Assignment**



### **IEC Logic Symbol**





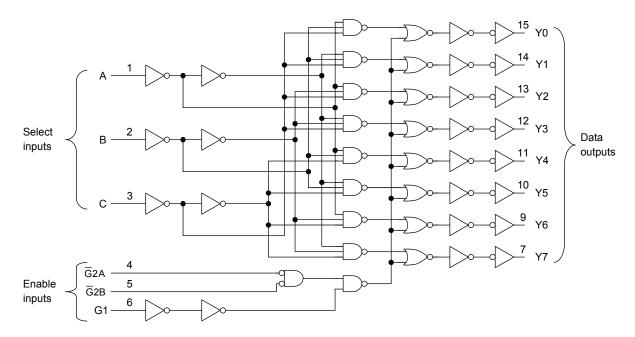
#### **Truth Table**

Inputs					Outputs										
Enable			Select		Y0	Y1	Y2	Y3	Y4	Y5	Y6	Y7	Selected Output		
G1	G2A	G2B	С	В	А	10	11	12	15	14	15	10	17		
L	Х	Х	Х	Х	Х	L	L	L	L	L	L	L	L	None	
Х	Н	Х	Х	Х	Х	L	L	L	L	L	L	L	L	None	
Х	х	Н	Х	Х	Х	L	L	L	L	L	L	L	L	None	
Н	L	L	L	L	L	Н	L	L	L	L	L	L	L	Y0	
Н	L	L	L	L	Н	L	Н	L	L	L	L	L	L	Y1	
Н	L	L	L	Н	L	L	L	Н	L	L	L	L	L	Y2	
Н	L	L	L	Н	Н	L	L	L	Н	L	L	L	L	Y3	
Н	L	L	Н	L	L	L	L	L	L	Н	L	L	L	Y4	
Н	L	L	Н	L	Н	L	L	L	L	L	Н	L	L	Y5	
Н	L	L	Н	Н	L	L	L	L	L	L	L	Н	L	Y6	
Н	L	L	Н	Н	Н	L	L	L	L	L	L	L	Н	Y7	

X: Don't care

## <u>TOSHIBA</u>

### Logic Diagram



#### Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to 7.0	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	IIК	-20	mA
Output diode current	I <sub>OK</sub>	±20	mA
DC output current	IOUT	±25	mA
DC V <sub>CC</sub> /ground current	ICC	±75	mA
Power dissipation	PD	180	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

### **Operating Range (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	2.0 to 5.5	V
Input voltage	VIN	0 to 5.5	V
Output voltage	Vout	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100 (V <sub>CC</sub> = 3.3 ± 0.3 V) 0 to 20 (V <sub>CC</sub> = 5 ± 0.5 V)	ns/V

Note: The operating range must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Symbol	Test Condition			٦	「a = 25°(	0	Ta = −40 to 85°C		Unit	
Characteristics	Cymbol					Тур.	Max	Min	Max	0	
High-level input voltage	VIH	_			1.50 V <sub>CC</sub> × 0.7	_	_	1.50 V <sub>CC</sub> × 0.7		V	
Low-level input voltage	VIL	_		2.0 3.0 to 5.5			0.50 V <sub>CC</sub> × 0.3		0.50 V <sub>CC</sub> × 0.3	V	
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA I <sub>OH</sub> = -4 mA	2.0 3.0 4.5 3.0	1.9 2.9 4.4 2.58	2.0 3.0 4.5		1.9 2.9 4.4 2.48		V	
			$I_{OH} = -8 \text{ mA}$	4.5	3.94	_	_	3.80	_		
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	l <sub>OL</sub> = 50 μΑ	2.0 3.0 4.5	-	0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1	v	
			I <sub>OL</sub> = 4 mA I <sub>OL</sub> = 8 mA	3.0 4.5	-		0.36 0.36		0.44 0.44		
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	_	±0.1	_	±1.0	μA	
Quiescent supply current	ICC	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	4.0	_	40.0	μA	

### AC Characteristics (input: tr = tf = 3 ns)

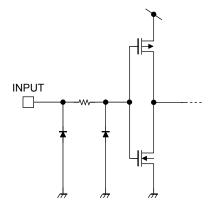
Characteristics	Symbol	Te	st Condition		Ta = 25°C			Ta = −40 to 85°C		Unit	
	- ,		V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Min	Max		
		_	3.3 ± 0.3	15	_	8.0	12.3	1.0	14.5	ns ns	
Propagation delay time	t <sub>pLH</sub>			50	_	10.5	15.8	1.0	18.0		
(A, B, C-Y)	t <sub>pHL</sub>		5.0 ± 0.5	15	—	5.5	8.1	1.0	9.5		
				50	—	7.0	10.1	1.0	11.5		
	t <sub>pLH</sub> t <sub>pHL</sub>	_	3.3 ± 0.3	15	—	8.1	12.8	1.0	15.0		
Propagation delay time				50	—	10.6	16.3	1.0	18.5		
(G1-Y)			5.0 ± 0.5	15	—	5.4	8.1	1.0	9.5		
				50	—	6.9	10.1	1.0	11.5		
	t <sub>pLH</sub> t <sub>pHL</sub>	_	3.3 ± 0.3	15	—	8.1	12.3	1.0	14.5	- ns	
Propagation delay time				50	—	10.6	15.8	1.0	18.0		
( <del>G</del> 2 - Y)			5.0 ± 0.5	15	_	5.7	8.1	1.0	9.5		
				50	_	7.2	10.1	1.0	11.5		
Input capacitance	C <sub>IN</sub>		_		_	4	_	_	10	pF	
Power dissipation capacitance	C <sub>PD</sub>			(Note)	_	37	_	_	_	pF	

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

#### Input Equivalent Circuit

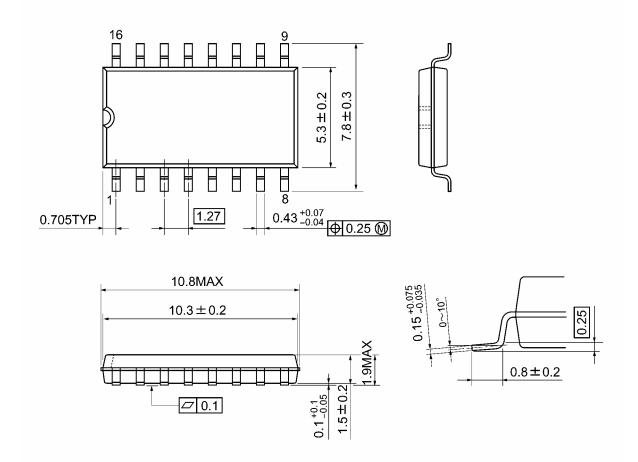




#### **Package Dimensions**

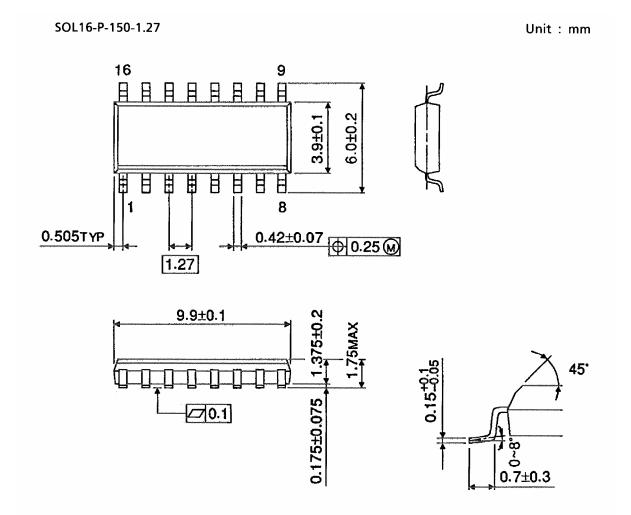
SOP16-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

#### Package Dimensions (Note)



Note: This package is not available in Japan.

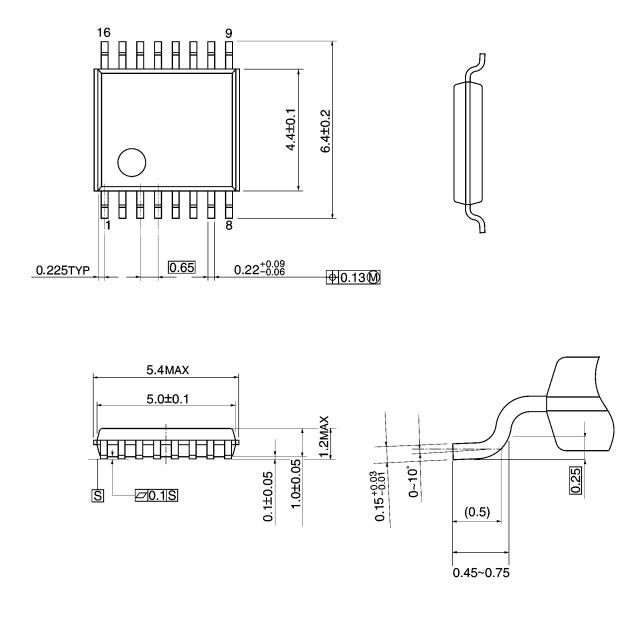
Weight: 0.13 g (typ.)

## **TOSHIBA**

### Package Dimensions

TSSOP16-P-0044-0.65A

Unit: mm



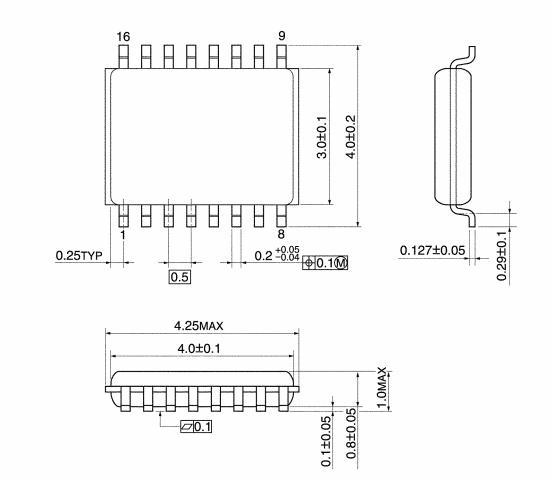
Weight: 0.06 g (typ.)

TOSHIBA

#### **Package Dimensions**

VSSOP16-P-0030-0.50

Unit: mm



Weight: 0.02 g (typ.)

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